LSI/CSI

RDD 104

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A3800

SELECTABLE 4 DECADE CMOS DIVIDER

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FEATURES:

- Selectable Divide by 10, 100, 1,000 or 10,000
- Clock Input Shaping Network Accepts Fast or Slow Edge Inputs
- Active Oscillator Network for External Crystal
- Square Wave Output
- Output TTL Compatible at +4.5 Volt Operation
- High Noise Immunity
- Reset
- All Inputs Protected
- +4.5 to +15 Volt Operation (V_{DD}-V_{SS})
- Low Power Dissipaton

PIN ASSIGNMENT - TOP VIEW
STANDARD 8 PIN MINI-DIP

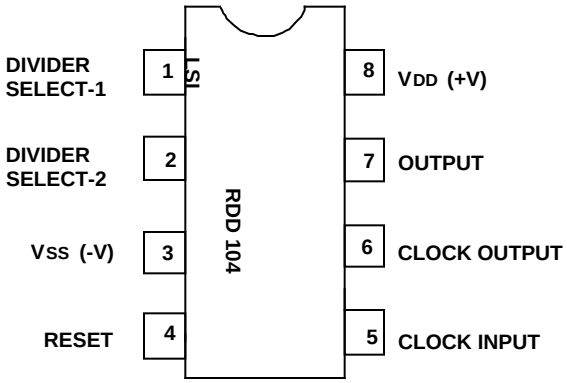

FIGURE 1

DESCRIPTION OF OPERATION:

The RDD104 is a monolithic CMOS four decade divider circuit that advances on each negative transition of the input clock pulse. When the reset input is high the circuit is cleared to zero. The clock input is applied to a three stage inverting amplifier network whose output is brought out so that an external crystal network can be used to form an oscillator circuit. If the clock output is not used,the amplifier acts as an input buffer. Two select inputs are provided which enables the circuit to divide by 10, 100, 1,000 or 10,000.

The Output Division is selected according to the following truth table:

DIVIDER SELECT INPUTS:		OUTPUT
SELECT 2	SELECT 1	DIVISION
0	0	10,000
0	1	1,000
1	0	100
1	1	10

MAXIMUM RATINGS:

PARAMETER	SYMBOL	VALUE	UNIT
Storage Temperature	T_{STG}	-65 to +150	°C
Operating Temperature	T_A	-40 to +85	°C
DC Supply Voltage	(V_{DD}-V_{SS})	+18	Volts
Voltage at any input	V_{IN}	V_{SS} -.5 to V_{DD} +.5	Volts

DC ELECTRICAL CHARACTERISTICS:
(All voltages referenced to Vss)

	V_{DD}	-40°C	+25°C	+85°C	UNIT
Quiescent Device Current	4.5V	10	10	300	uA Max
	10V	20	20	600	uA Max
Output Voltage, Low Level	4.5V	.01	.01	.05	V Min
	10V	.01	.01	.05	V Min
High Level	4.5V	4.49	4.49	4.45	V Max
	10V	9.99	9.99	9.95	V Max
Input Noise Immunity	4.5V	1.3	1.3	1.3	V Min
(Low and High)	10V	3.0	3.0	3.0	V Min
Output Drive Current:					
N Channel Sink Current	4.5V	2.3	1.9	1.6	mA Min
(V_{OUT} = Vss +0.4V)	10V	5.0	4.0	3.5	mA Mi
P Channel Source Current Min	4.5V	1.1	.95	.8	mA
(V_{OUT} = V_{DD} -1V) Min	10V	2.5	2.1	1.8	mA
Input Capacitance (any input)			5.0		pF Max

DYNAMIC ELECTRICAL CHARACTERISTICS:

(C_L = 50pF, Input Rise and Fall Times = 20ns except for Clock, unless otherwise specified.)

	V_{DD}	MIN	MAX	UNIT
Clock Input Frequency	4.5V	0	1.5	MHz
	10V	0	4.0	MHz
	15V	0	6.0	MHz
Clock Input Rise & Fall Times	4.5 to 15V	-	No Limit	
Clock Input Rise & Fall Time, C_L = 15pF	4.5V	-	140	ns
	10V	-	70	ns
Clock Output Propagation Delay, C_L = 15pF	4.5V	-	300	ns
	10V	-	150	ns
Output Rise & Fall Times	4.5V	-	400	ns
	10V	-	200	ns
Propagation Delay to Output	4.5V	-	1500	ns
	10V	-	750	ns
Reset Pulse Width	4.5V	800	-	ns
	10V	400	-	ns
Reset Removal Time	4.5V	-	500	ns
	10V	-	250	ns
Reset Propagation Delay to Output	4.5V	-	1400	ns
	10V	-	700	ns
Select Input Setup Time	4.5V	-	800	ns
	10V	-	400	ns

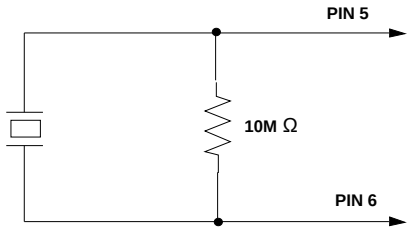

FIGURE 2.
MINIMUM PARTS OSCILLATOR CIRCUIT

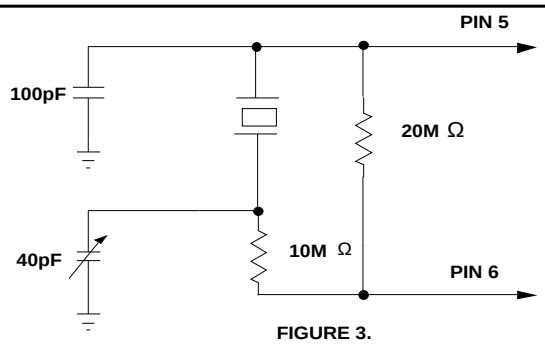

FIGURE 3.
TYPICAL OSCILLATOR CIRCUIT WITH TRIM -1 MHZ AND BELOW

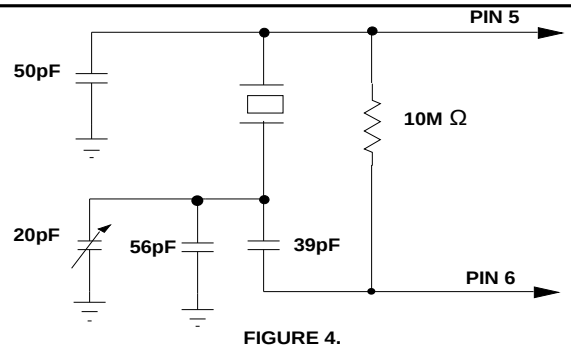

FIGURE 4.
TYPICAL OSCILLATOR CIRCUIT WITH TRIM - ABOVE 1 MHZ

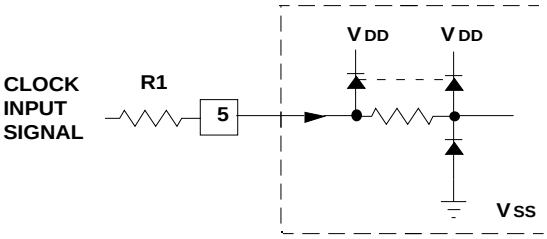

FIGURE 5. TYPICAL INPUT
If input signals are less than V_{SS} or greater than V_{DD}, a series input resistor, R1, should be used to limit the maximum input current to 2 milliamperes.

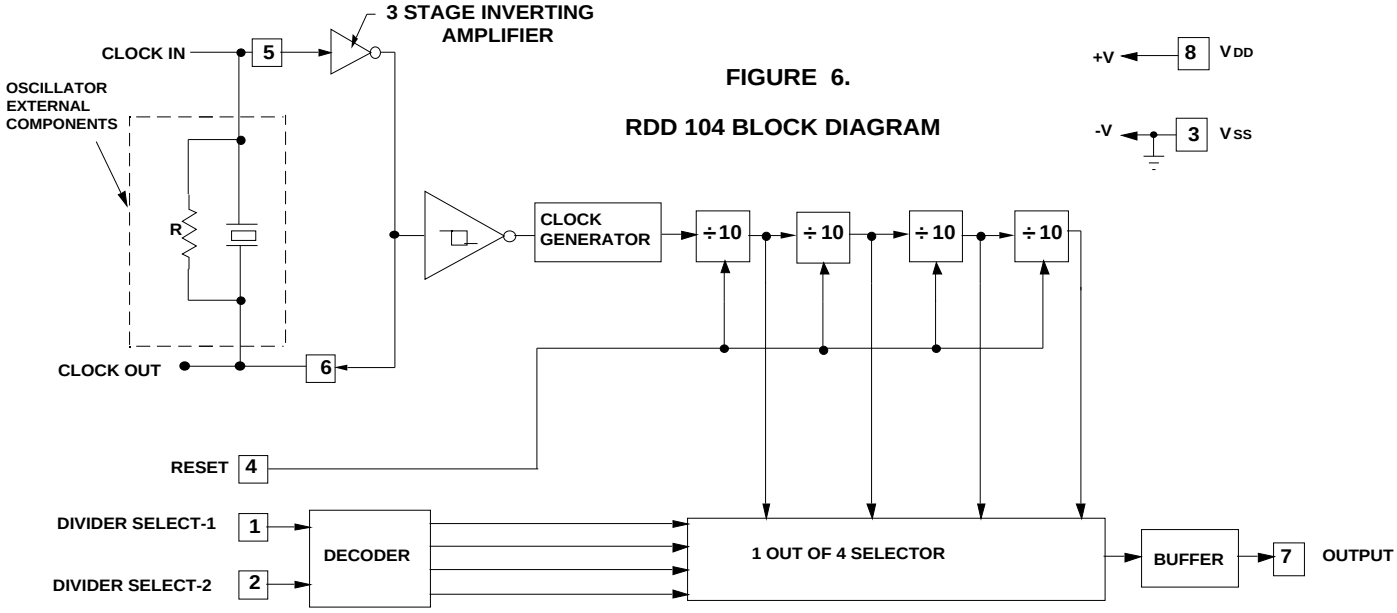

FIGURE 6.

RDD 104 BLOCK DIAGRAM